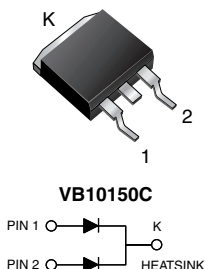


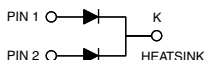
# High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low  $V_F = 0.63 \text{ V}$  at  $I_F = 3 \text{ A}$

TMBS®  
D<sup>2</sup>PAK (TO-263AB)



VB10150C



## LINKS TO ADDITIONAL RESOURCES



3D Models

## PRIMARY CHARACTERISTICS

|                               |                               |
|-------------------------------|-------------------------------|
| $I_{F(AV)}$                   | 2 x 5.0 A                     |
| $V_{RRM}$                     | 150 V                         |
| $I_{FSM}$                     | 60 A                          |
| $V_F$ at $I_F = 10 \text{ A}$ | 0.69 V                        |
| $T_J \text{ max.}$            | 150 °C                        |
| Package                       | D <sup>2</sup> PAK (TO-263AB) |
| Circuit configuration         | Common cathode                |

## FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

## TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

## MECHANICAL DATA

**Case:** D<sup>2</sup>PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating  
Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102  
M3 suffix meets JESD 201 class 1A whisker test

**Polarity:** as marked

**Mounting Torque:** 10 in-lbs maximum

## MAXIMUM RATINGS ( $T_A = 25 \text{ °C}$ unless otherwise noted)

| PARAMETER                                                                                      | SYMBOL         | VB10150C    | UNIT       |
|------------------------------------------------------------------------------------------------|----------------|-------------|------------|
| Maximum repetitive peak reverse voltage                                                        | $V_{RRM}$      | 150         | V          |
| Maximum average forward rectified current (fig. 1) <span style="float:right">per device</span> | $I_{F(AV)}$    | 10          | A          |
| <span style="float:right">per diode</span>                                                     |                | 5.0         |            |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode   | $I_{FSM}$      | 60          |            |
| Voltage rate of change (rated $V_R$ )                                                          | $dV/dt$        | 10 000      | V/ $\mu$ s |
| Operating junction and storage temperature range                                               | $T_J, T_{STG}$ | -55 to +150 | °C         |

## ELECTRICAL CHARACTERISTICS ( $T_A = 25 \text{ °C}$ unless otherwise noted)

| PARAMETER                                              | TEST CONDITIONS        |                         | SYMBOL         | TYP. | MIN. | UNIT |
|--------------------------------------------------------|------------------------|-------------------------|----------------|------|------|------|
| Instantaneous forward voltage per diode <sup>(1)</sup> | I <sub>F</sub> = 3.0 A | T <sub>A</sub> = 25 °C  | V <sub>F</sub> | 0.82 | -    | V    |
|                                                        | I <sub>F</sub> = 5.0 A |                         |                | 0.99 | 1.41 |      |
|                                                        | I <sub>F</sub> = 3.0 A | T <sub>A</sub> = 125 °C |                | 0.63 | -    |      |
|                                                        | I <sub>F</sub> = 5.0 A |                         |                | 0.69 | 0.75 |      |
| Reverse current per diode <sup>(2)</sup>               | V <sub>R</sub> = 100 V | T <sub>A</sub> = 25 °C  | I <sub>R</sub> | 0.5  | -    | μA   |
|                                                        |                        | T <sub>A</sub> = 125 °C |                | 0.5  | -    | mA   |
|                                                        | V <sub>R</sub> = 150 V | T <sub>A</sub> = 25 °C  |                | -    | 100  | μA   |
|                                                        |                        | T <sub>A</sub> = 125 °C |                | 1    | 10   | mA   |

### Notes

<sup>(1)</sup> Pulse test: 300  $\mu$ s pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width  $\leq 40 \text{ ms}$

**THERMAL CHARACTERISTICS** ( $T_A = 25\text{ }^{\circ}\text{C}$  unless otherwise noted)

| PARAMETER                            | SYMBOL          | VB10150C | UNIT                 |
|--------------------------------------|-----------------|----------|----------------------|
| Typical thermal resistance per diode | $R_{\theta JC}$ | 4.0      | $^{\circ}\text{C/W}$ |

**ORDERING INFORMATION** (Example)

| PACKAGE                       | PREFERRED P/N  | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |
|-------------------------------|----------------|-----------------|--------------|---------------|---------------|
| D <sup>2</sup> PAK (TO-263AB) | VB10150C-M3/4W | 1.39            | 4W           | 50/tube       | Tube          |
| D <sup>2</sup> PAK (TO-263AB) | VB10150C-M3/8W | 1.39            | 8W           | 800/reel      | Tape and reel |

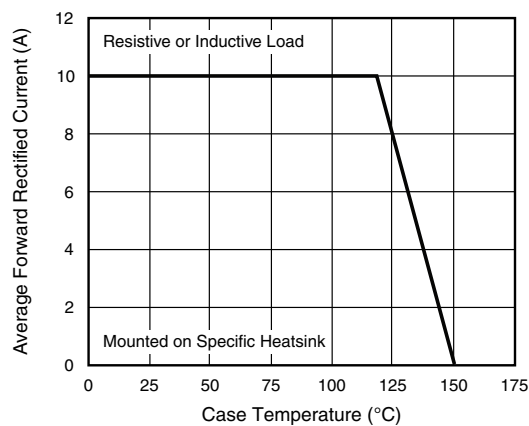
**RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25\text{ }^{\circ}\text{C}$  unless otherwise noted)

Fig. 1 - Maximum Forward Current Derating Curve

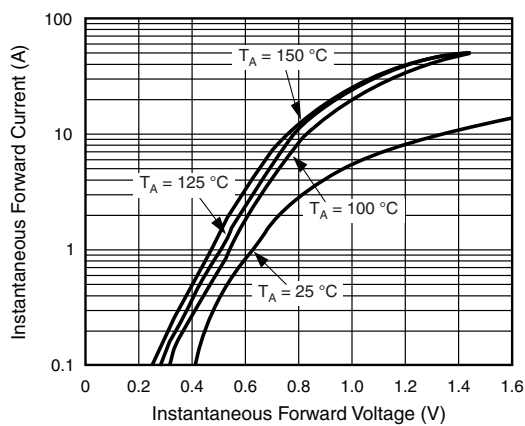


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

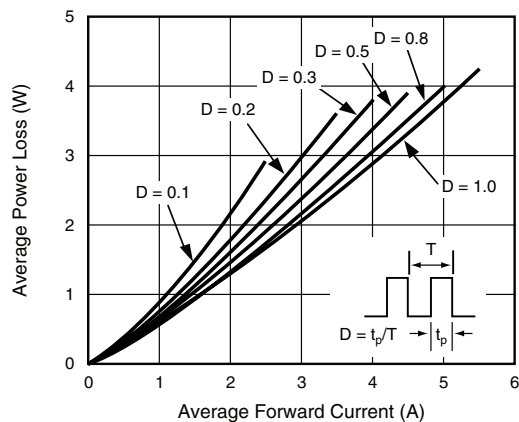


Fig. 2 - Forward Power Dissipation Characteristics Per Diode

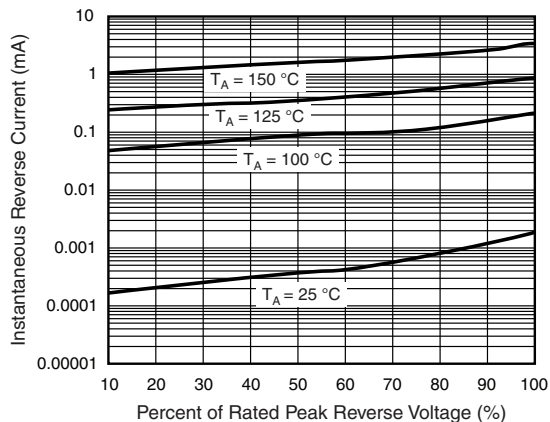


Fig. 4 - Typical Reverse Characteristics Per Diode

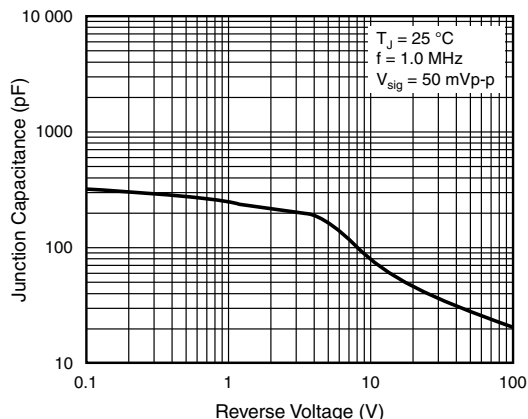


Fig. 5 - Typical Junction Capacitance Per Diode

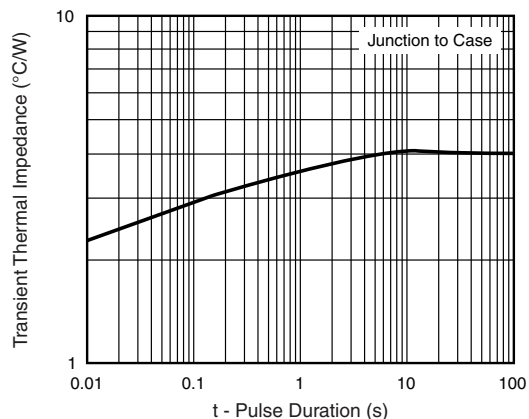
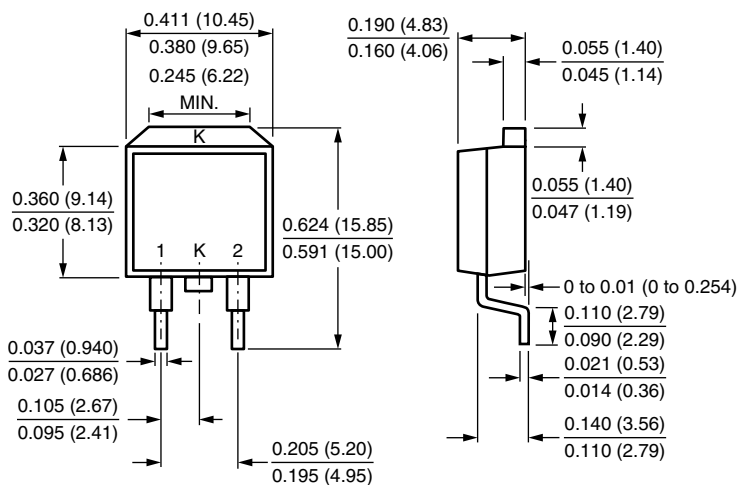


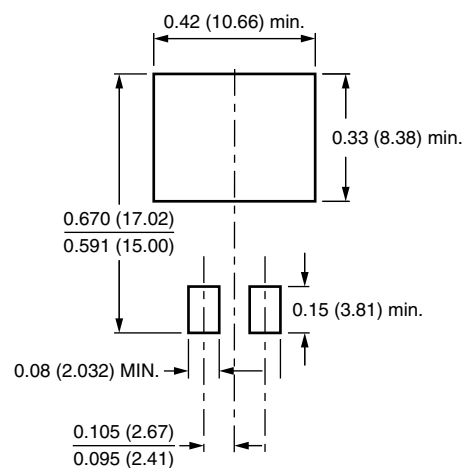
Fig. 6 - Typical Transient Thermal Impedance Per Diode

### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

#### D<sup>2</sup>PAK (TO-263AB)



#### Mounting Pad Layout





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